Qualcomm

RF360
Europe GmbH

Data sheet

SAW multiplexer
LTE + EN-DC 4G/5G band 1 + band 3

Series/type:	B8927
Ordering code:	B39212B8927P810
Date:	February 26, 2020
Version:	2.0

DCN: 80-PA243-449 Rev. A

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1 Application

- Low-loss SAW multiplexer for mobile telephone LTE + EN-DC 4G/5G Band 1 + Band 3 systems.
- Usable pass bands: 60 MHz for Band 1 and 75 MHz for Band 3.
- High out of band selectivity
- High TX-RX isolation
- Terminating impedance 50 Ω
- Unbalanced to unbalanced operation

2 Features

- Package size $2.5_{\pm 0.1}$ mm × $2.0_{\pm 0.1}$ mm
- Package height 0.65 mm (max.)
- Approximate weight 4 mg
- RoHS compatible
- Package for Surface Mount Technology (SMT)
- Ni/Au-plated terminals
- Electrostatic Sensitive Device (ESD)
- Moisture Sensitivity Level 3 (MSL3)

3 Package

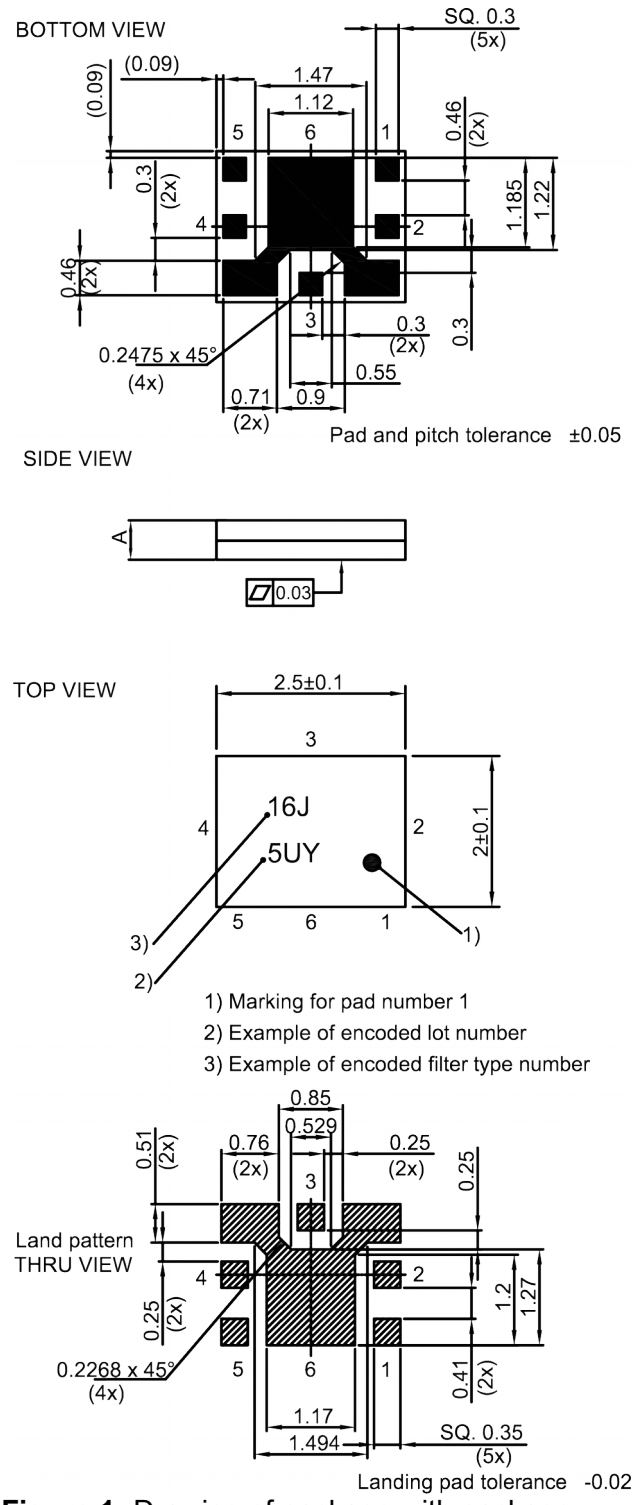

Figure 1: Drawing of package with package height A = 0.65 mm (max.). See Sec. Package information (p. 37).

4 Pin configuration

- 1 TX (B1)
- 2 TX (B3)
- 3 ANT (B1 & B3)
- 4 RX (B1)
- 5 RX (B3)
- 6 Ground

5 Matching circuit

- L_{p4} = 9.5 nH
- L_{s1} = 2.4 nH
- L_{s2} = 1.0 nH
- L_{s5} = 3.8 nH

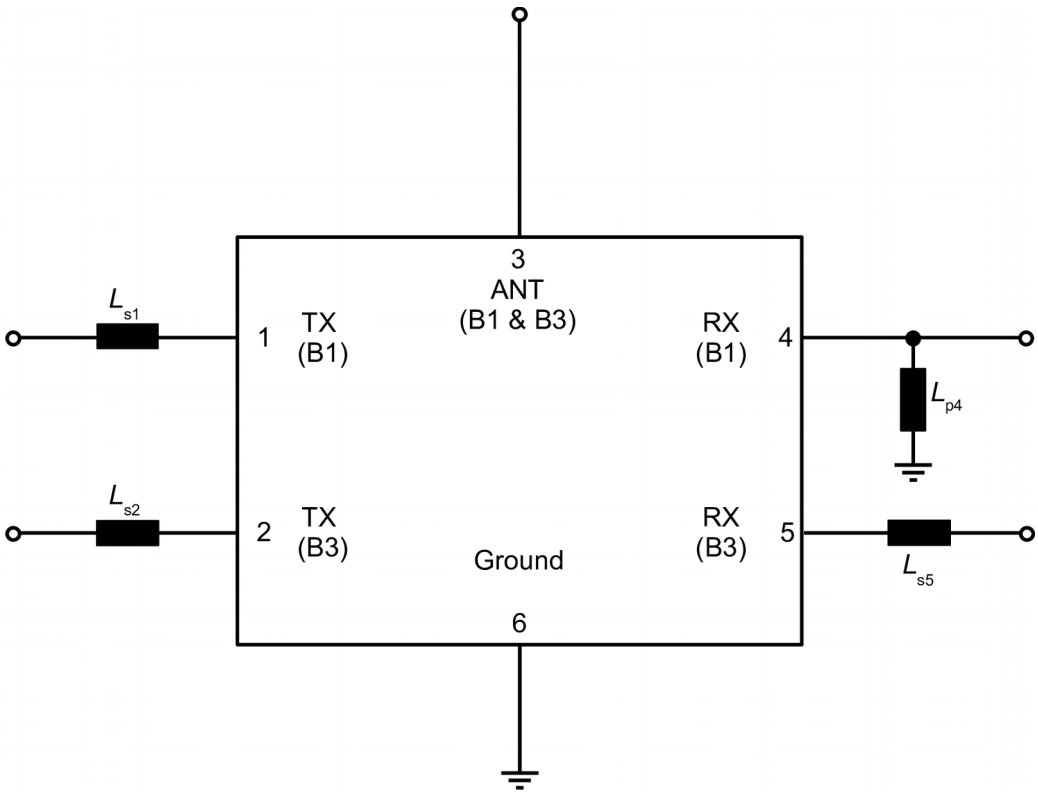

Figure 2: Schematic of matching circuit.

External shunt inductor for ESD protection is recommended at any ports towards antenna.

6 Characteristics LTE + EN-DC 4G/5G B1

6.1 TX – ANT

Temperature range for specification	T_{SPEC}	= −30 °C ... +85 °C
B1 TX terminating impedance	$Z_{B1\ TX}$	= 50 Ω + 2.4 nH[1)]
ANT terminating impedance	Z_{ANT}	= 50 Ω
B1 RX terminating impedance	$Z_{B1\ RX}$	= 50 Ω // 9.5 nH[1)]

Characteristics LTE + EN-DC 4G/5G B1 TX – ANT				min. for T_{SPEC}	typ. @ +25 °C	max. for T_{SPEC}	
Maximum insertion attenuation			α_{max}				
	1920... 1980	MHz		—	1.2	2.1	dB
Amplitude ripple (p-p)			$\Delta\alpha$				
	1920... 1980	MHz		—	0.4	1.3	dB
Maximum VSWR			$VSWR_{max}$				
@ B1 TX port	1920... 1980	MHz		—	1.3	2.0	
@ ANT port	1920... 1980	MHz		—	1.3	2.0	
Minimum attenuation							
	10... 1574	MHz	α_{min}	40	52	—	dB
	703... 748	MHz	α_{min}	40	64	—	dB
	758... 894	MHz	α_{min}	40	61	—	dB
	880... 960	MHz	α_{min}	40	60	—	dB
	1166... 1187	MHz	α_{min}	44	56	—	dB
	1427.9... 1447.9	MHz	α_{min}	40	52	—	dB
	1452... 1511	MHz	α_{min}	45	53	—	dB
	1559... 1607	MHz	α_{min}	43	54	—	dB
	1710... 1785	MHz	α_{min}	40	51	—	dB
	1805... 1880	MHz	α_{min}	45	60	—	dB
	1880... 1895	MHz	α_{min}	10	12	—	dB
	2010... 2025	MHz	α_{min} [2)]	20[2)]	34	—	dB
	2110... 2170	MHz	α_{min}	45	64	—	dB
	2300... 2400	MHz	α_{min}	45	62	—	dB
	2400... 2500	MHz	α_{min}	40	64	—	dB
	2496... 2690	MHz	$\alpha_{INT,min}$ [3)]	38	43	—	dB
	2500... 2570	MHz	α_{min}	45	64	—	dB
	2620... 2690	MHz	$\alpha_{INT,min}$ [3)]	38	43	—	dB
	3300... 3800	MHz	α_{min}	40	52	—	dB
	3300... 4200	MHz	$\alpha_{INT,min}$ [3)]	40	52	—	dB
	4200... 5925	MHz	α_{min}	40	49	—	dB
	4400... 5000	MHz	α_{min}	40	62	—	dB
	5150... 5925	MHz	α_{min}	40	49	—	dB

1) See Sec. Matching circuit (p. 6).
2) Valid for temperature T = +15 °C...+85 °C.

3) Integrated attenuation α_{INT}: Averaged power $|S_{ij}|^2$ over the center 4.5 MHz of LTE 5 MHz (25 RB) channels.

6.2 ANT – RX

Temperature range for specification	T_{SPEC}	= −30 °C ... +85 °C
B1 TX terminating impedance	$Z_{B1\ TX}$	= 50 Ω + 2.4 nH[1)]
ANT terminating impedance	Z_{ANT}	= 50 Ω
B1 RX terminating impedance	$Z_{B1\ RX}$	= 50 Ω // 9.5 nH[1)]

Characteristics LTE + EN-DC 4G/5G B1 ANT – RX				min. for T_{SPEC}	typ. @ +25 °C	max. for T_{SPEC}	
Maximum insertion attenuation			α_{max}				
	2110... 2170	MHz		—	1.1	2.0	dB
Amplitude ripple (p-p)			$\Delta\alpha$				
	2110... 2170	MHz		—	0.4	1.2	dB
Maximum VSWR			$VSWR_{max}$				
@ ANT port	2110... 2170	MHz		—	1.5	2.0	
@ B1 RX port	2110... 2170	MHz		—	1.5	2.0	
Minimum attenuation							
	10... 2025	MHz	α_{min}	33	43	—	dB
	190	MHz	α_{min}	50	97	—	dB
	699... 748	MHz	α_{min}	40	71	—	dB
	703... 862	MHz	α_{min}	40	68	—	dB
	880... 915	MHz	α_{min}	40	67	—	dB
	1055... 1085	MHz	α_{min}	48	65	—	dB
	1427.9... 1463	MHz	α_{min}	40	67	—	dB
	1710... 1785	MHz	α_{min}	45	59	—	dB
	1730... 1790	MHz	α_{min}	40	59	—	dB
	1920... 1980	MHz	α_{min}	45	57	—	dB
	2015... 2025	MHz	α_{min}	37	45	—	dB
	2025... 2050	MHz	α_{min}	22	48	—	dB
	2050... 2075	MHz	α_{min}	8	10	—	dB
	2230... 2255	MHz	α_{min}	12	59	—	dB
	2255... 6000	MHz	α_{min}	25	44	—	dB
	2400... 2500	MHz	α_{min}	38	53	—	dB
	2500... 2570	MHz	α_{min}	45	51	—	dB
	3300... 3800	MHz	α_{min}	40	45	—	dB
	3300... 4200	MHz	$\alpha_{INT,min}$ [2)]	31	45	—	dB
	4220... 4340	MHz	α_{min}	35	53	—	dB
	4400... 5500	MHz	α_{min}	35	52	—	dB
	5150... 5950	MHz	α_{min}	35	52	—	dB

1) See Sec. Matching circuit (p. 6).
2) Integrated attenuation α_{INT}: Averaged power $|S_{ij}|^2$ over the center 18 MHz of LTE 20 MHz (100 RB) channels.

6.3 TX – RX

Temperature range for specification	T_{SPEC}	= −30 °C ... +85 °C
B1 TX terminating impedance	$Z_{B1\ TX}$	= 50 Ω + 2.4 nH[1)]
ANT terminating impedance	Z_{ANT}	= 50 Ω
B1 RX terminating impedance	$Z_{B1\ RX}$	= 50 Ω // 9.5 nH[1)]

Characteristics LTE + EN-DC 4G/5G B1 TX – RX			**min.** for T_{SPEC}	**typ.** @ +25 °C	**max.** for T_{SPEC}	
Minimum isolation		α_{min}				
	1574... 1577	MHz	40	67	—	dB
	1920... 1980	MHz	55	58	—	dB
	2110... 2170	MHz	55	63	—	dB
	3830... 3970	MHz	30	66	—	dB
	5750... 5950	MHz	30	65	—	dB

1) See Sec. Matching circuit (p. 6).

7 Characteristics LTE + EN-DC 4G/5G B3

7.1 TX – ANT

Temperature range for specification	T_{SPEC}	= −30 °C ... +85 °C
B3 TX terminating impedance	$Z_{B3\ TX}$	= 50 Ω + 1.0 nH[1)]
ANT terminating impedance	Z_{ANT}	= 50 Ω
B3 RX terminating impedance	$Z_{B3\ RX}$	= 50 Ω + 3.8 nH[1)]

Characteristics LTE + EN-DC 4G/5G B3 TX – ANT				**min.** for T_{SPEC}	**typ.** @ +25 °C	**max.** for T_{SPEC}	
Maximum insertion attenuation			α_{max}				
	1710... 1785	MHz		—	1.5	2.8	dB
Amplitude ripple (p-p)			Δα				
	1710... 1785	MHz		—	0.8	2.0	dB
Maximum VSWR			$VSWR_{max}$				
@ B3 TX port	1710... 1785	MHz		—	1.4	2.0	
@ ANT port	1710... 1785	MHz		—	1.5	2.0	
Minimum attenuation			α_{min}				
	10... 1566	MHz		40	50	—	dB
	703... 960	MHz		40	56	—	dB
	1166... 1187	MHz		44	52	—	dB
	1427.9... 1449.9	MHz		40	52	—	dB
	1452... 1511	MHz		45	52	—	dB
	1559... 1607	MHz		45	50	—	dB
	1805... 1880	MHz		45	70	—	dB
	1920... 1980	MHz		40	47	—	dB
	2110... 2170	MHz		45	60	—	dB
	2300... 2400	MHz		38	43	—	dB
	2400... 2500	MHz		40	48	—	dB
	2496... 2690	MHz		45	56	—	dB
	2500... 2570	MHz		40	56	—	dB
	2620... 2690	MHz		45	59	—	dB
	3300... 4200	MHz		35	42	—	dB
	3420... 3570	MHz		35	42	—	dB
	4400... 5000	MHz		35	45	—	dB
	5130... 5925	MHz		35	43	—	dB

[1)] See Sec. Matching circuit (p. 6).

7.2 ANT – RX

Temperature range for specification	T_{SPEC}	= −30 °C ... +85 °C
B3 TX terminating impedance	$Z_{B3\ TX}$	= 50 Ω + 1.0 nH[1)]
ANT terminating impedance	Z_{ANT}	= 50 Ω
B3 RX terminating impedance	$Z_{B3\ RX}$	= 50 Ω + 3.8 nH[1)]

Characteristics LTE + EN-DC 4G/5G B3 ANT – RX				**min.** for T_{SPEC}	**typ.** @ +25 °C	**max.** for T_{SPEC}	
Maximum insertion attenuation			α_{max}				
	1805... 1880	MHz		—	1.9	2.8	dB
Amplitude ripple (p-p)			$\Delta\alpha$				
	1805... 1880	MHz		—	1.0	1.9	dB
Maximum VSWR			$VSWR_{max}$				
@ ANT port	1805... 1880	MHz		—	1.4	2.0	
@ B3 RX port	1805... 1880	MHz		—	1.4	2.0	
Minimum attenuation							
	10... 1720	MHz	α_{min}	45	54	—	dB
	95	MHz	α_{min}	50	88	—	dB
	703... 915	MHz	α_{min}	45	68	—	dB
	1427.9... 1463	MHz	α_{min}	40	59	—	dB
	1615... 1690	MHz	α_{min}	40	62	—	dB
	1710... 1785	MHz	α_{min}	45	59	—	dB
	1720... 1755	MHz	α_{min}	12	59	—	dB
	1785... 1790	MHz	α_{min}	10	21	—	dB
	1920... 1980	MHz	α_{min}	45	60	—	dB
	1940... 1965	MHz	α_{min}	12	60	—	dB
	1965... 6000	MHz	α_{min}	25	39	—	dB
	2400... 2500	MHz	α_{min}	35	61	—	dB
	2496... 2690	MHz	$\alpha_{INT,min}$ [2)]	37	41	—	dB
	2500... 2570	MHz	$\alpha_{INT,min}$ [2)]	37	41	—	dB
	3300... 4200	MHz	α_{min}	35	50	—	dB
	3610... 3760	MHz	α_{min}	35	50	—	dB
	4400... 5000	MHz	α_{min}	35	65	—	dB
	5150... 5925	MHz	α_{min}	35	65	—	dB

1) See Sec. Matching circuit (p. 6).
2) Integrated attenuation α_{INT}: Averaged power $|S_{ij}|^2$ over the center 4.5 MHz of LTE 5 MHz (25 RB) channels.

7.3 TX – RX

Temperature range for specification	T_{SPEC}	= −30 °C ... +85 °C
B3 TX terminating impedance	$Z_{B3\ TX}$	= 50 Ω + 1.0 nH[1)]
ANT terminating impedance	Z_{ANT}	= 50 Ω
B3 RX terminating impedance	$Z_{B3\ RX}$	= 50 Ω + 3.8 nH[1)]

Characteristics LTE + EN-DC 4G/5G B3 TX – RX			**min.** for T_{SPEC}	**typ.** @ +25 °C	**max.** for T_{SPEC}	
Minimum isolation	α_{min}					
	1710... 1785	MHz	55	59	—	dB
	1805... 1880	MHz	55	71	—	dB

1) See Sec. Matching circuit (p. 6).

8 Cross-isolations

8.1 LTE + EN-DC 4G/5G B1 TX – LTE + EN-DC 4G/5G B3 RX

Temperature range for specification T_{SPEC} = −30 °C ... +85 °C
B1 TX terminating impedance $Z_{B1\ TX}$ = 50 Ω + 2.4 nH[1)]
B3 RX terminating impedance $Z_{B3\ RX}$ = 50 Ω + 3.8 nH[1)]

Characteristics cross-isolation LTE + EN-DC 4G/5G B1 TX – LTE + EN-DC 4G/5G B3 RX			**min.** for T_{SPEC}	**typ.** @ +25 °C	**max.** for T_{SPEC}	
Minimum cross-isolation	α_{min}					
1805... 1880	MHz		55	62	—	dB
1920... 1980	MHz		55	60	—	dB

1) See Sec. Matching circuit (p. 6).

8.2 LTE + EN-DC 4G/5G B3 TX – LTE + EN-DC 4G/5G B1 RX

Temperature range for specification T_{SPEC} = −30 °C ... +85 °C
B3 TX terminating impedance $Z_{B3\ TX}$ = 50 Ω + 1.0 nH[1)]
B1 RX terminating impedance $Z_{B1\ RX}$ = 50 Ω // 9.5 nH[1)]

Characteristics cross-isolation **LTE + EN-DC 4G/5G B3 TX – LTE + EN-DC 4G/5G B1 RX**			**min.** for T_{SPEC}	**typ.** @ +25 °C	**max.** for T_{SPEC}	
Minimum cross-isolation	α_{min}					
1710... 1785	MHz		55	62	—	dB
2110... 2170	MHz		55	60	—	dB

1) See Sec. Matching circuit (p. 6).

9 Maximum ratings

Operable temperature	T_{OP} = −30 °C ... +85 °C	
Storage temperature	T_{STG} [1] = −40 °C ... +85 °C	
DC voltage	$\lvert V_{DC} \rvert$ [2] = 0 V (max.)	
ESD voltage		
	V_{ESD} [3] = 75 V (max.)	Machine model.
	V_{ESD} [4] = 150 V (max.)	Human body model.
	V_{ESD} [5] = 700 V (max.)	Charged device model.
Input power	P_{IN}	
@ B1 TX port: 1920 ... 1980 MHz	30 dBm	Continuous wave for 5000 h @ 50 °C.
@ B3 TX port: 1710 ... 1785 MHz	30 dBm	Continuous wave for 5000 h @ 50 °C.

1) Not valid for packaging material. Storage temperature for packaging material is −25 °C to +40 °C.
2) In case of applied DC voltage blocking capacitors are mandatory.
3) According to JESD22-A115B (MM – Machine Model), 10 negative & 10 positive pulses.
4) According to JESD22-A114F (HBM – Human Body Model), 1 negative & 1 positive pulse.
5) According to JESD22-C101C (CDM – Field Induced Charged Device Model), 3 negative & 3 positive pulses.

10 Transmission coefficients LTE + EN-DC 4G/5G B1

10.1 TX – ANT

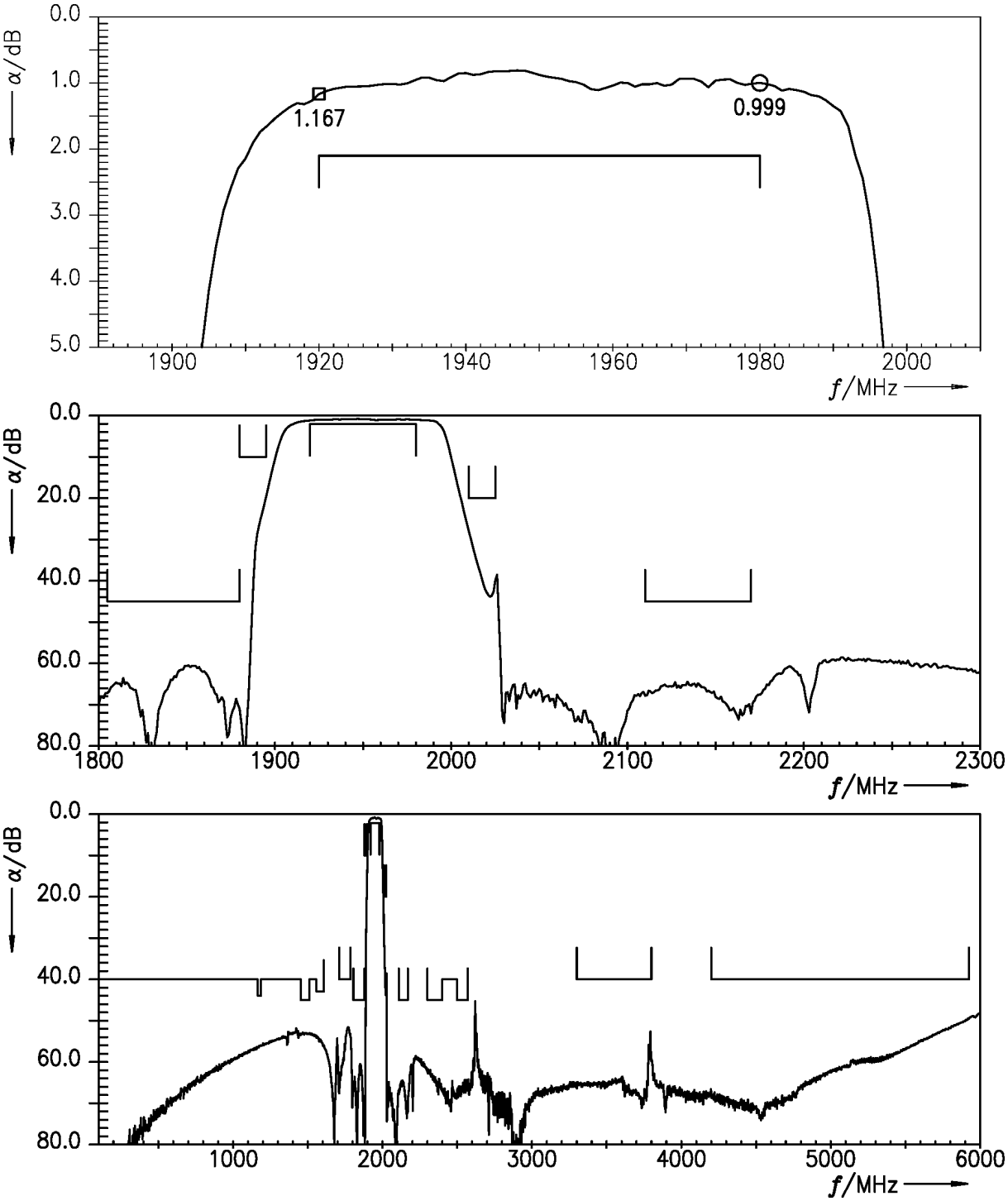

Figure 3: Attenuation TX – ANT.

10.2 ANT – RX

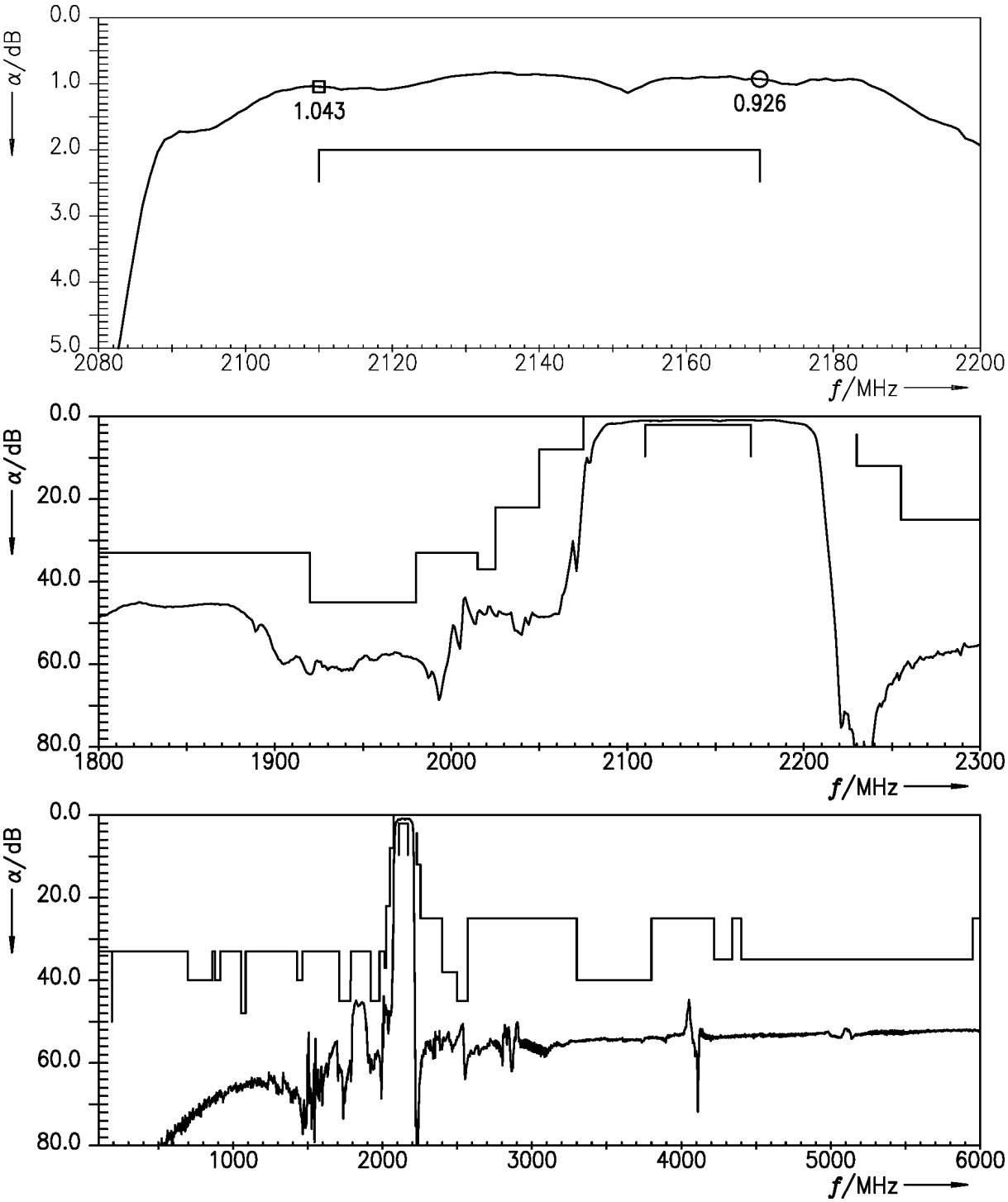

Figure 4: Attenuation ANT – RX.

10.3 TX – RX

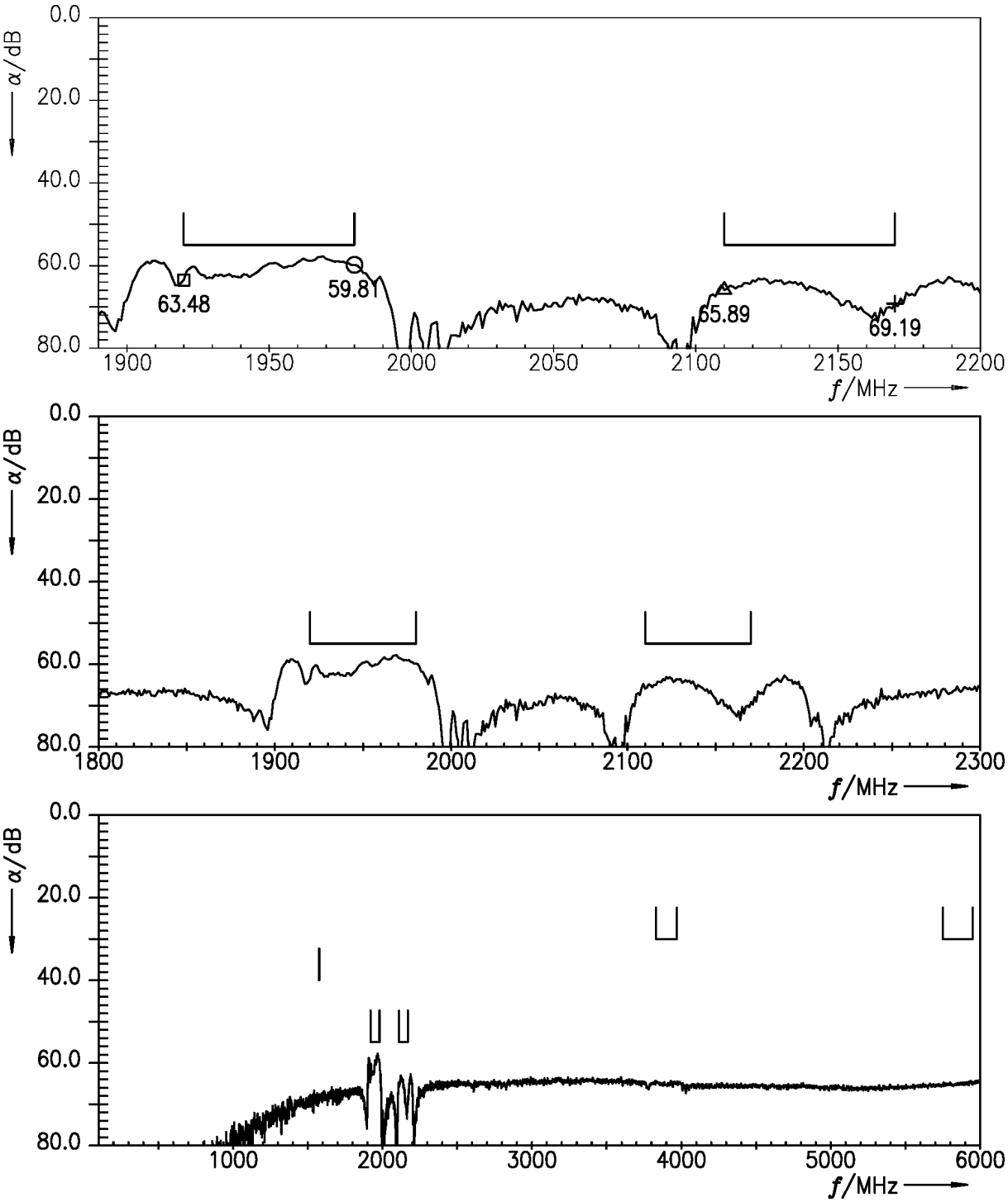

Figure 5: Isolation TX – RX.

11 Transmission coefficient (LTE) LTE + EN-DC 4G/5G B1

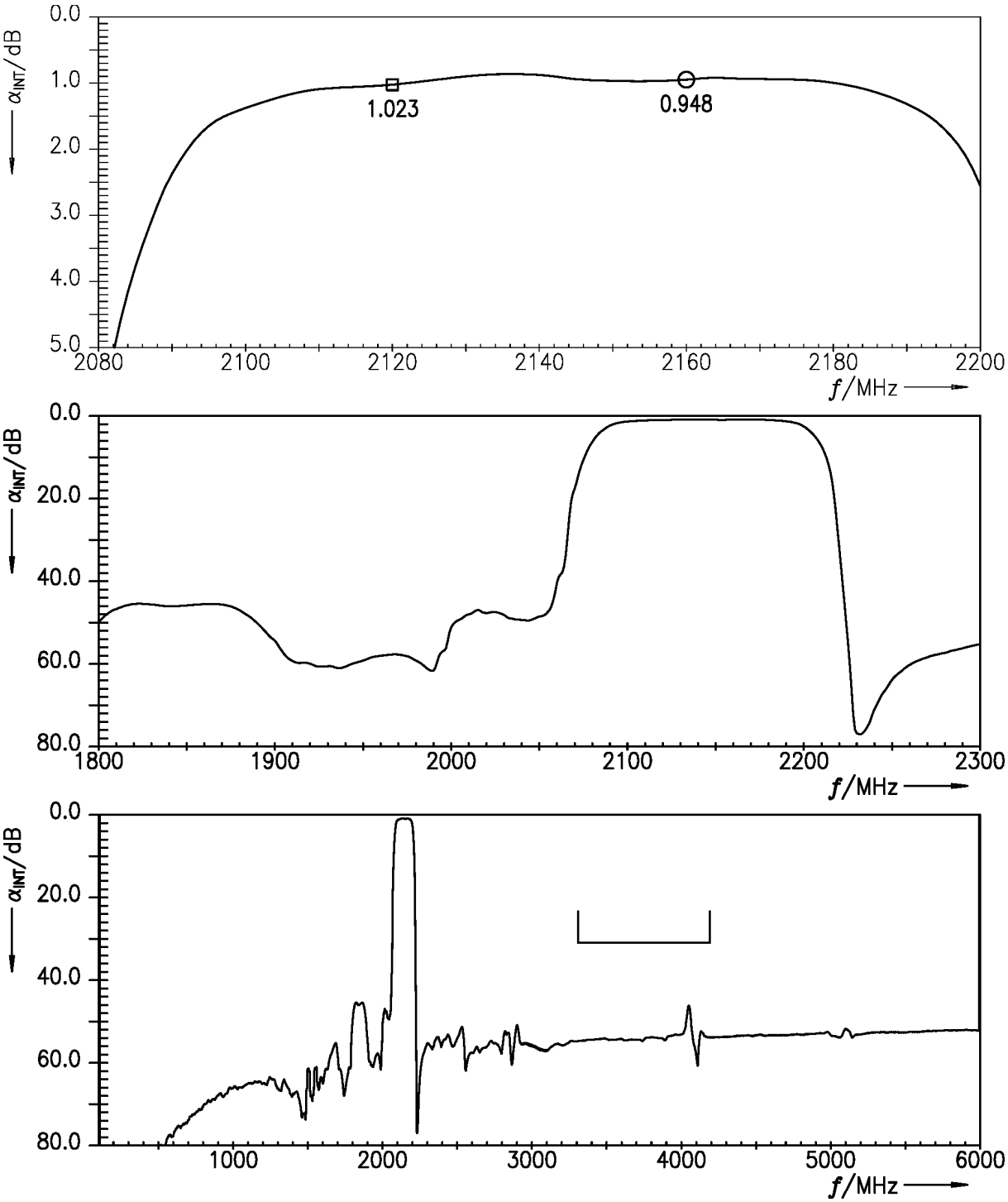

Figure 6: Attenuation (LTE) (integration window = 20 MHz) ANT – RX.

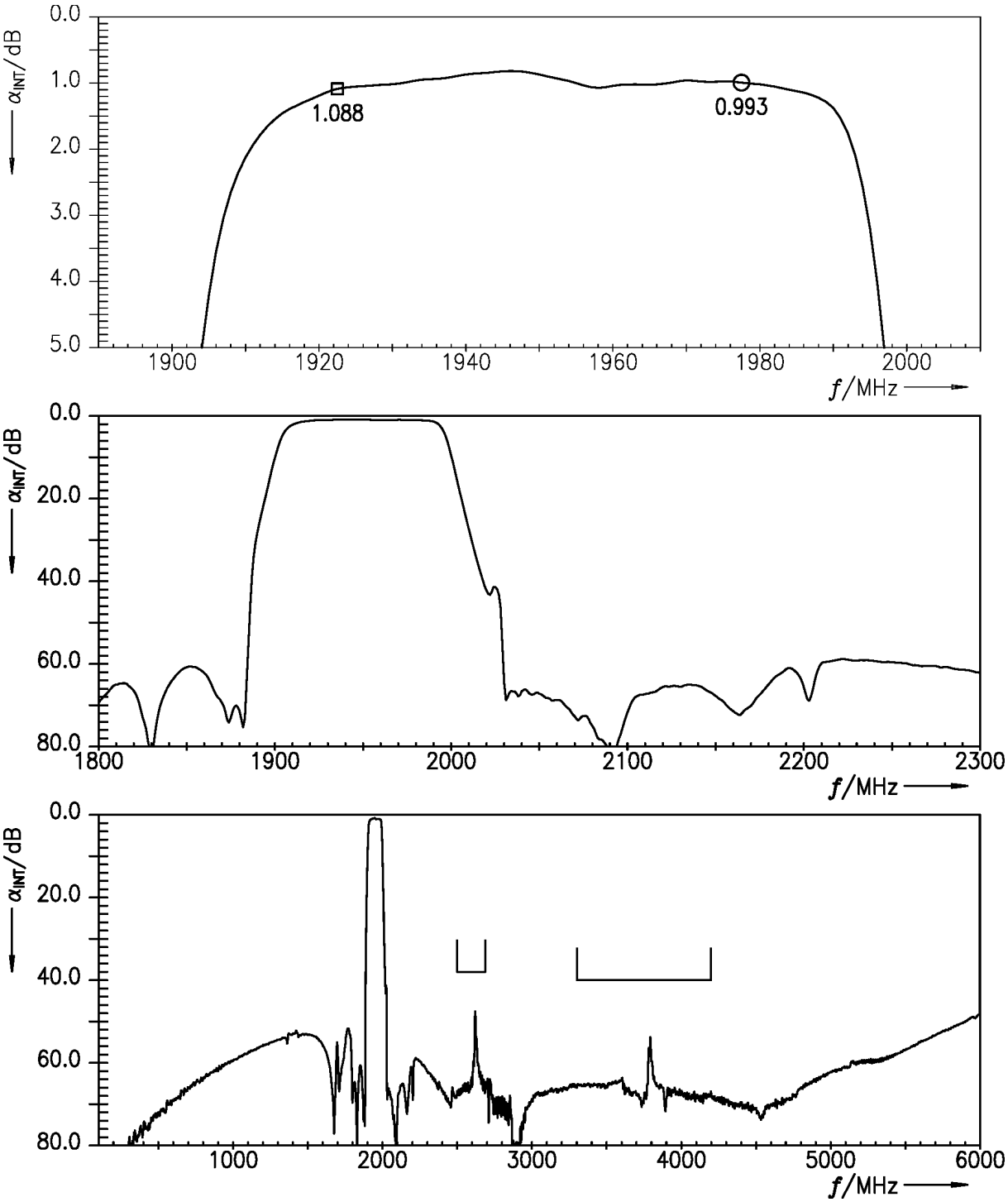

Figure 7: Attenuation (LTE) (integration window = 5 MHz) TX – ANT.

12 Reflection coefficients LTE + EN-DC 4G/5G B1

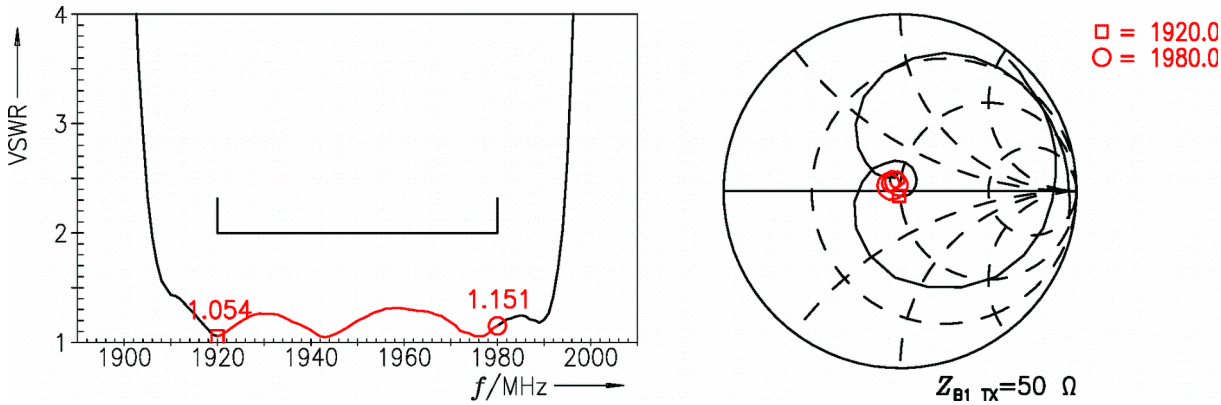

Figure 8: Reflection coefficient at B1 TX port.

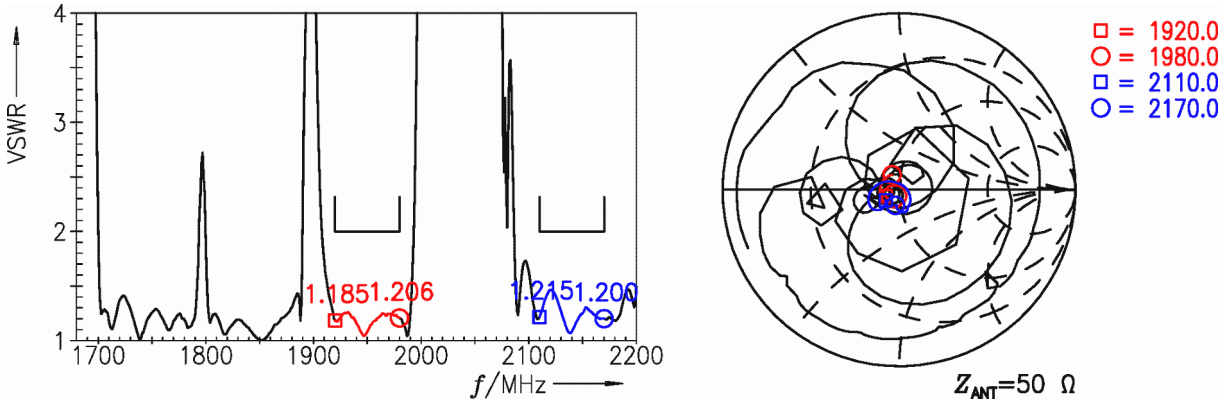

Figure 9: Reflection coefficient at ANT port.

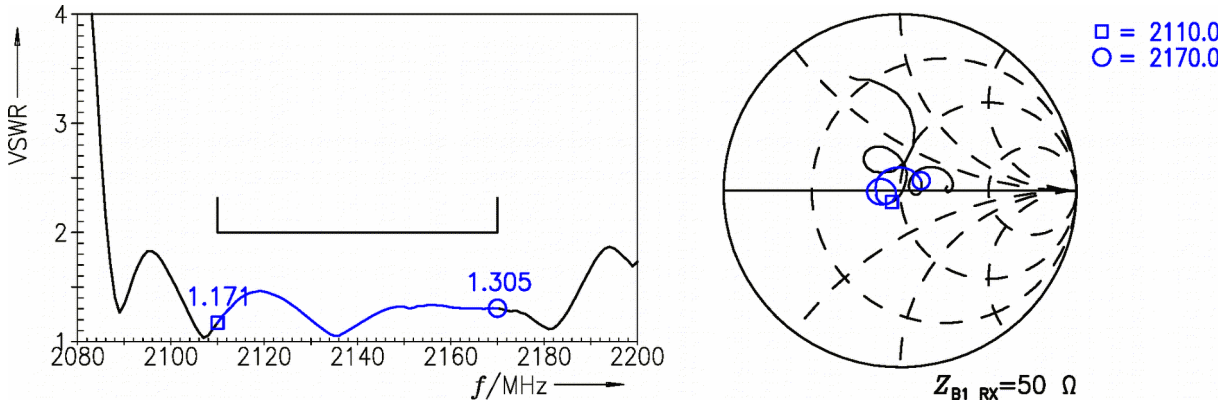

Figure 10: Reflection coefficient at B1 RX port.

13 Transmission coefficients LTE + EN-DC 4G/5G B3

13.1 TX – ANT

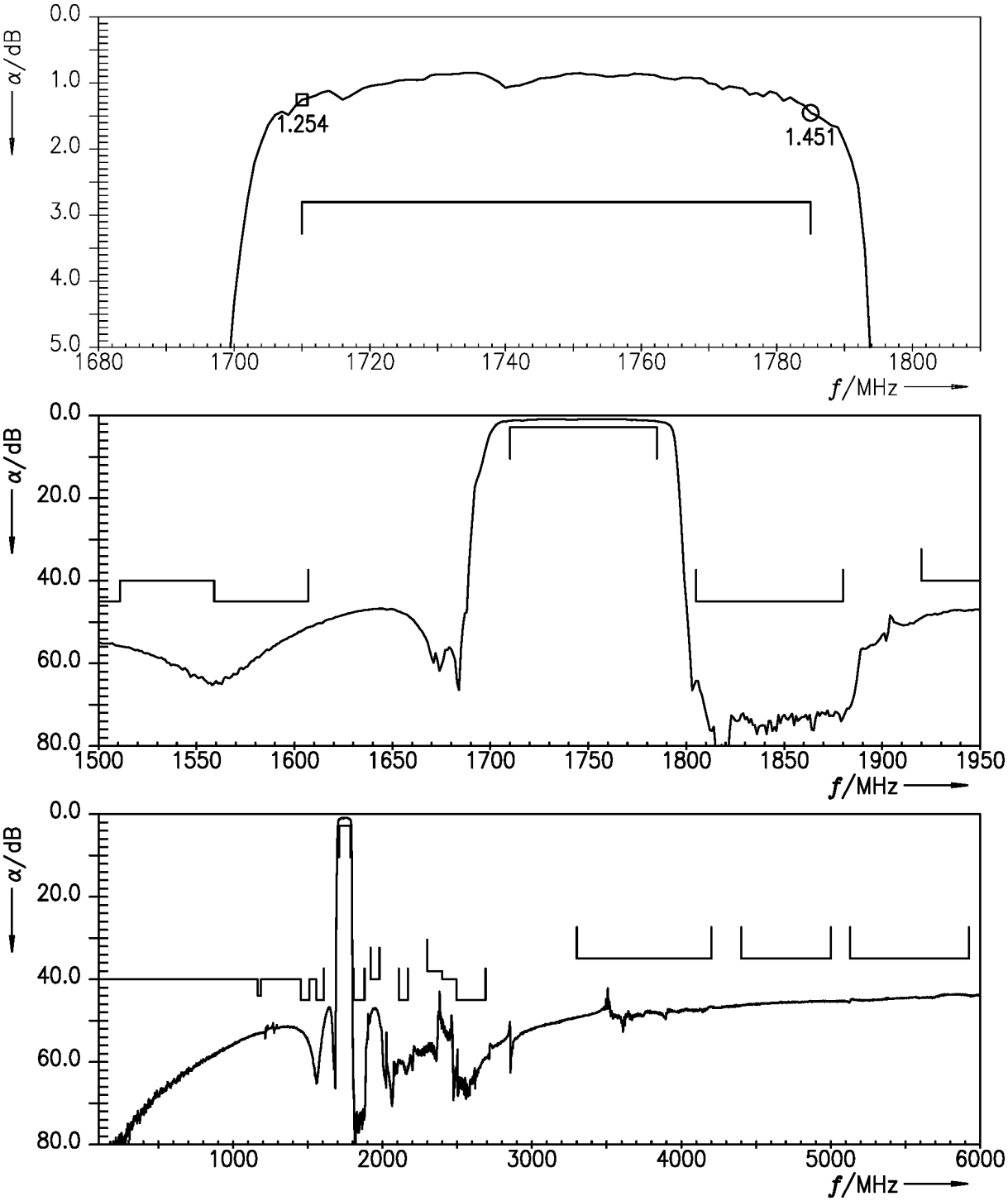

Figure 11: Attenuation TX – ANT.

13.2 ANT – RX

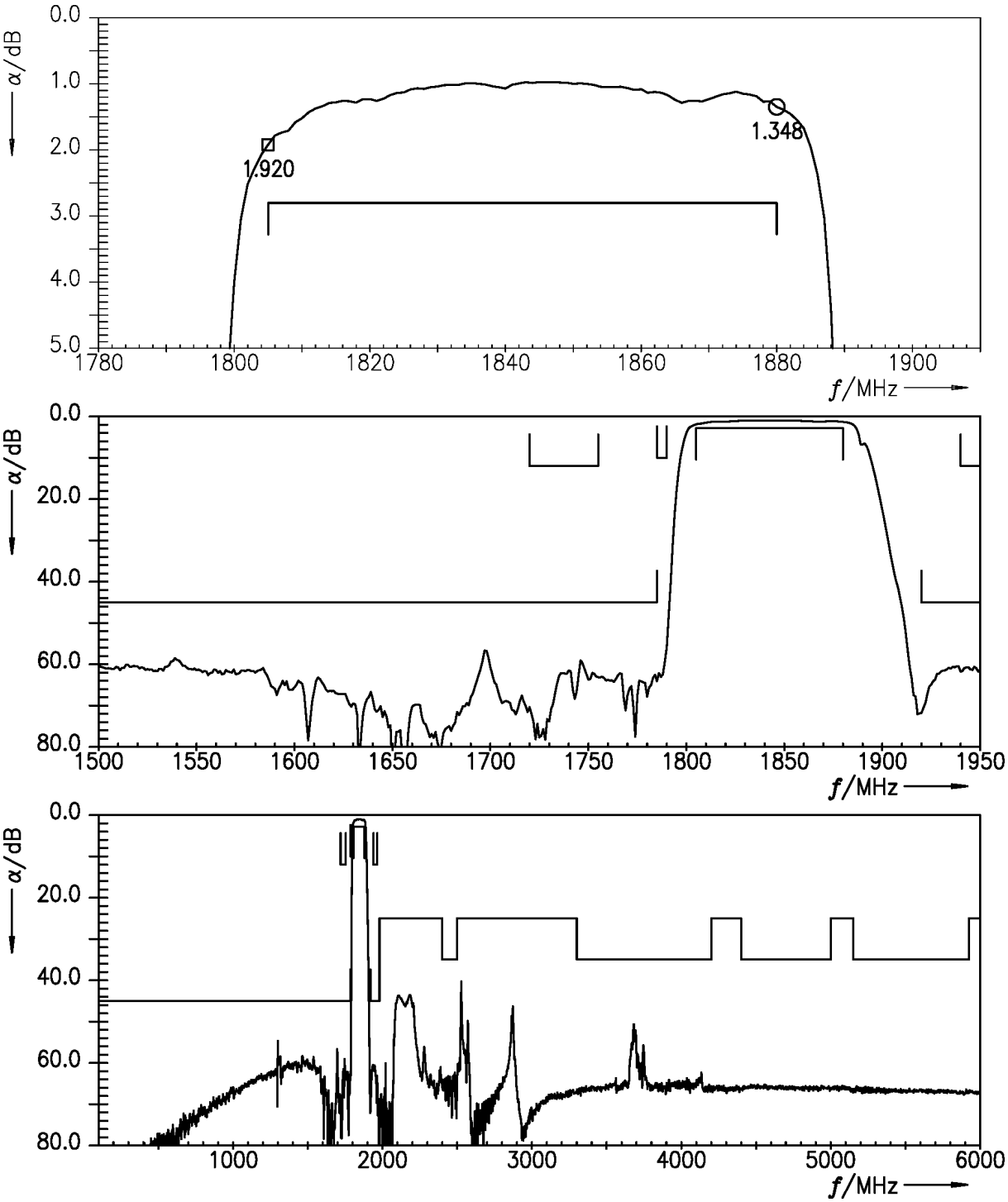

Figure 12: Attenuation ANT – RX.

13.3 TX – RX

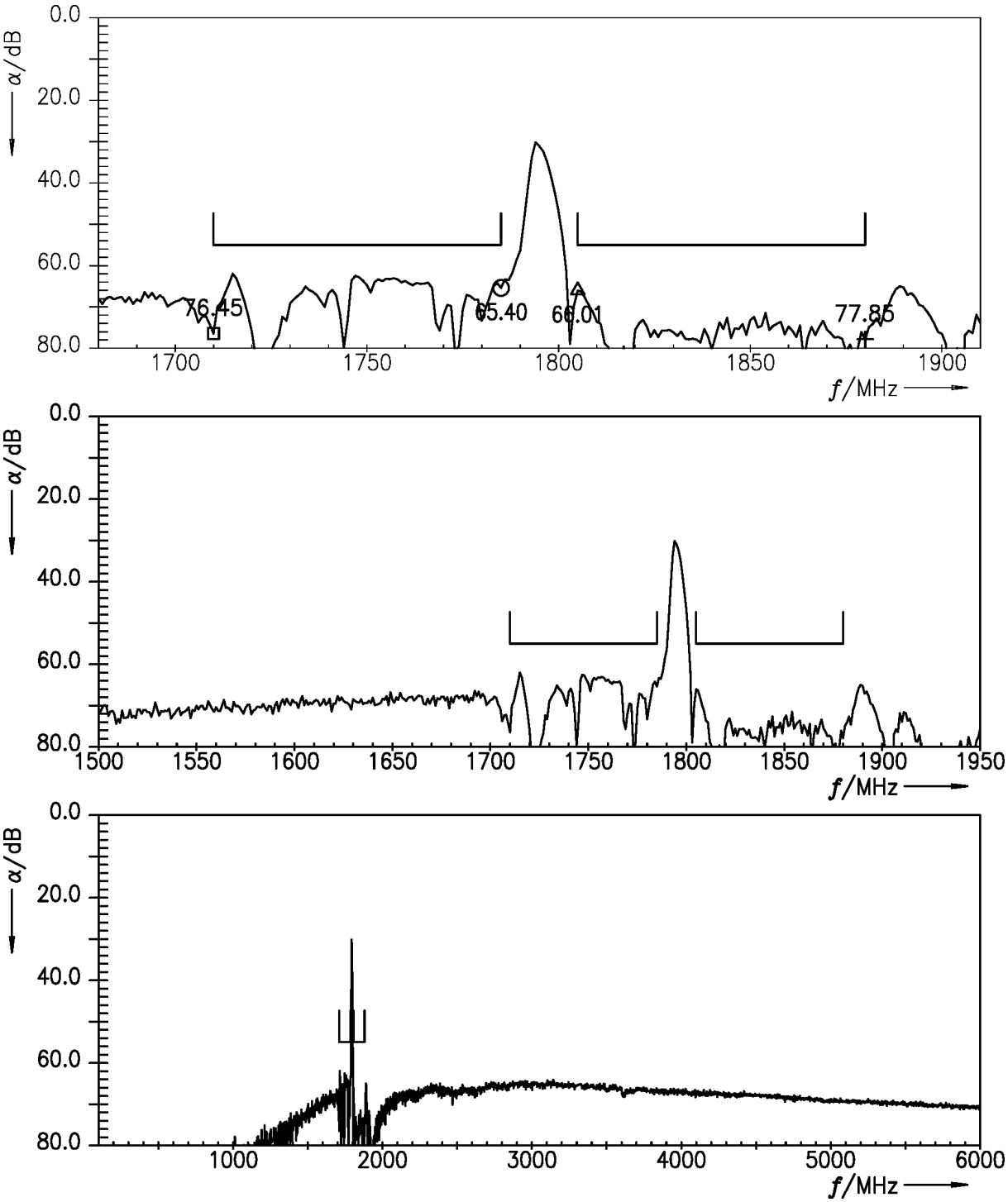

Figure 13: Isolation TX – RX.

14 Transmission coefficient (LTE) LTE + EN-DC 4G/5G B3

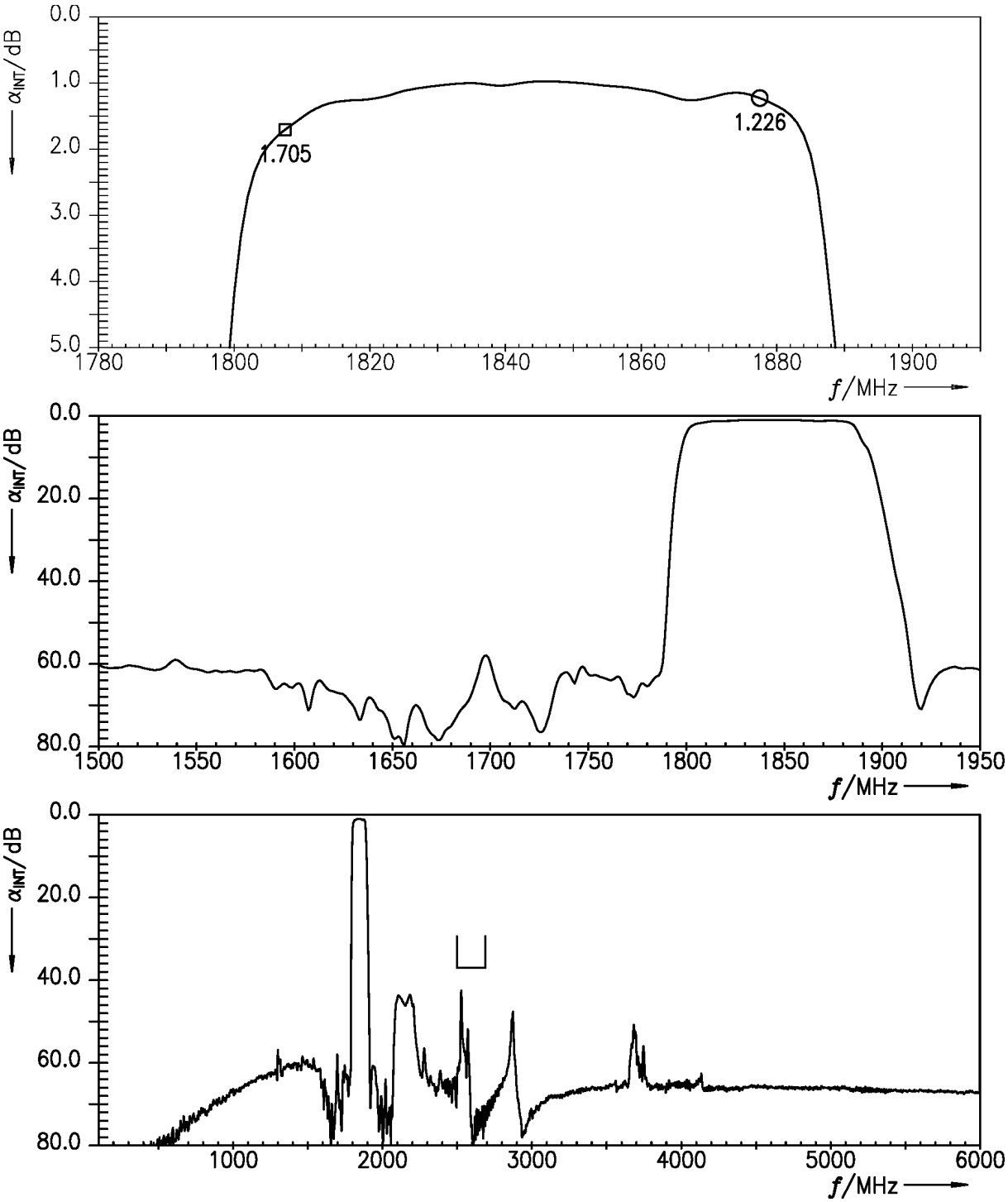

Figure 14: Attenuation (LTE) (integration window = 5 MHz) ANT – RX.

15 Reflection coefficients LTE + EN-DC 4G/5G B3

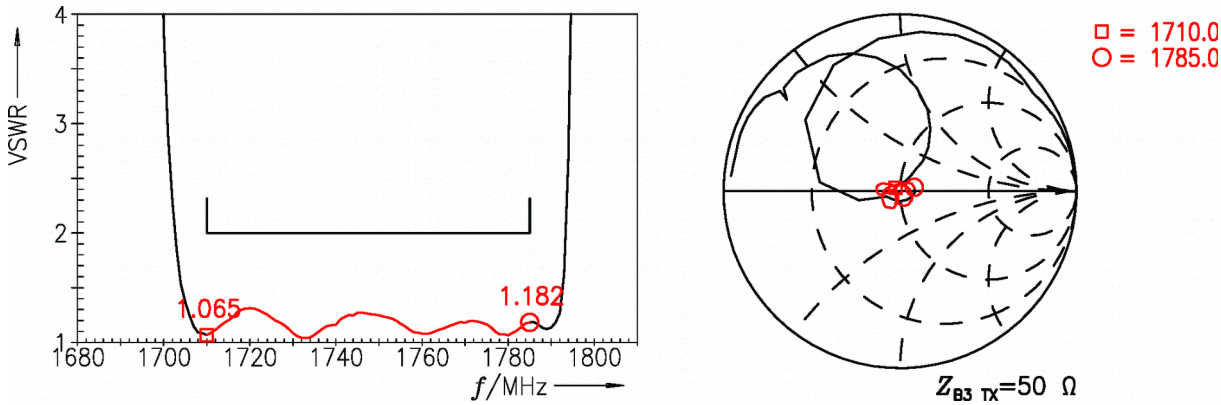

Figure 15: Reflection coefficient at B3 TX port.

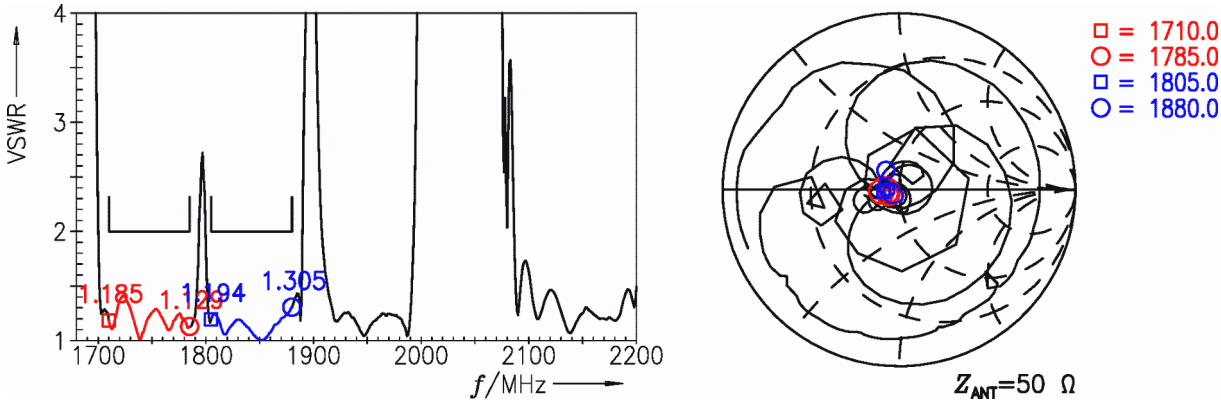

Figure 16: Reflection coefficient at ANT port.

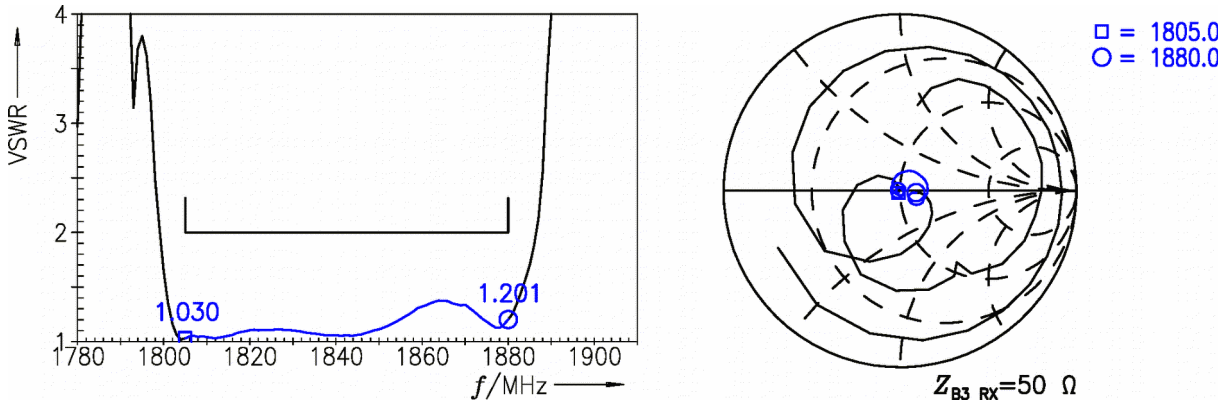

Figure 17: Reflection coefficient at B3 RX port.

16 Transmission coefficients cross-isolations

16.1 LTE + EN-DC 4G/5G B1 TX – LTE + EN-DC 4G/5G B3 RX

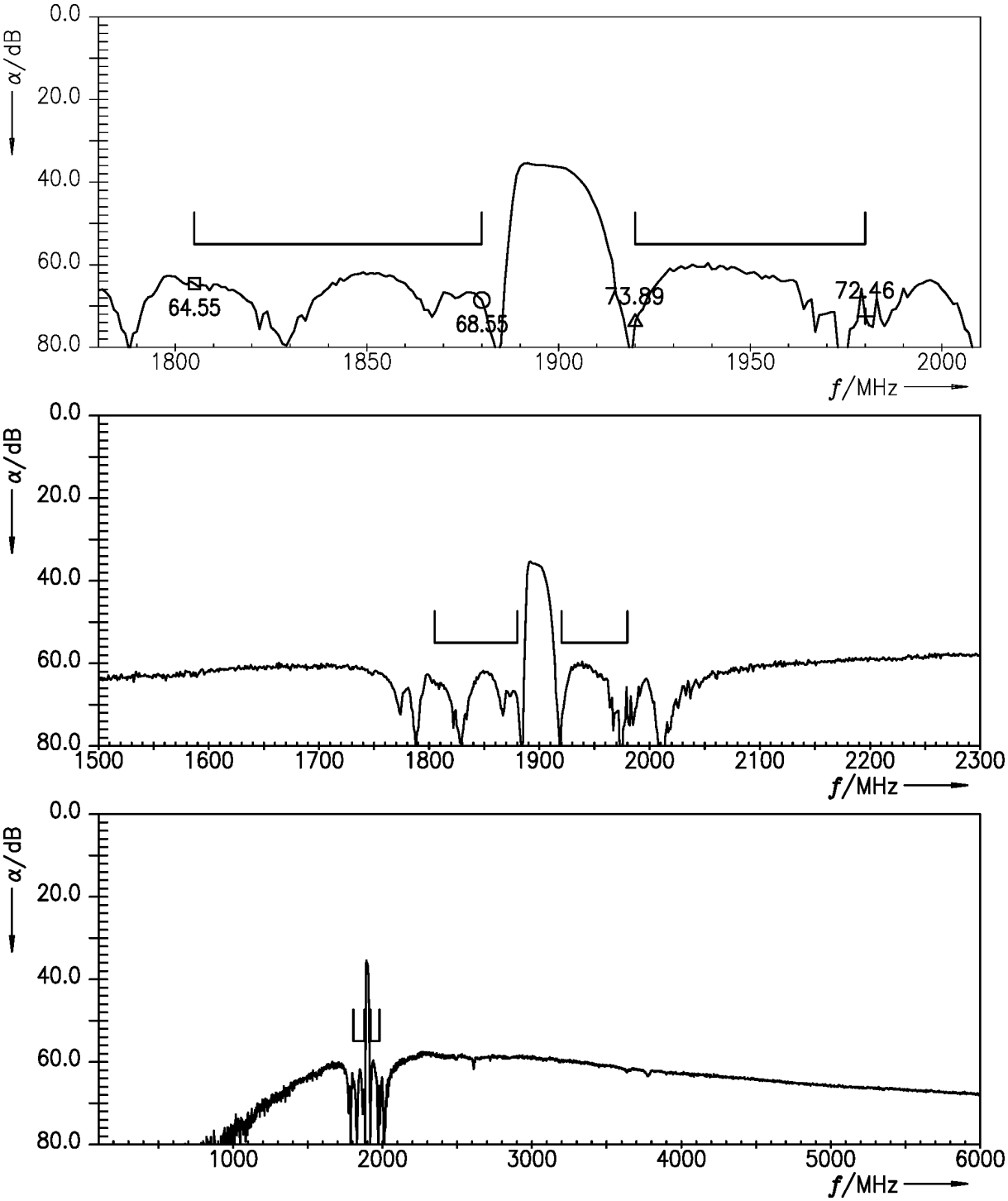

Figure 18: Cross-isolation LTE + EN-DC 4G/5G B1 TX – LTE + EN-DC 4G/5G B3 RX.

16.2 LTE + EN-DC 4G/5G B3 TX – LTE + EN-DC 4G/5G B1 RX

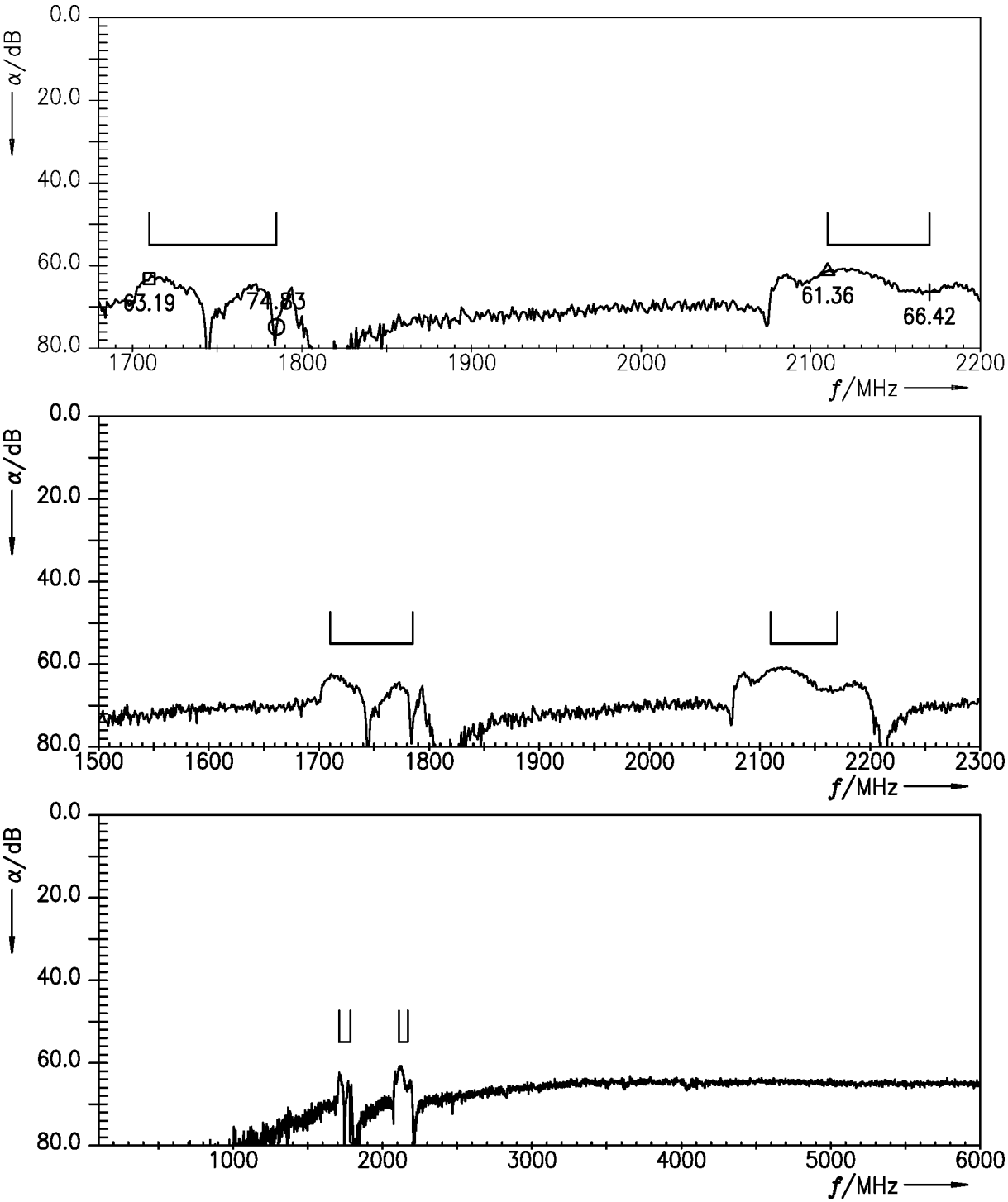

Figure 19: Cross-isolation LTE + EN-DC 4G/5G B3 TX – LTE + EN-DC 4G/5G B1 RX.

17 Packing material

17.1 Tape

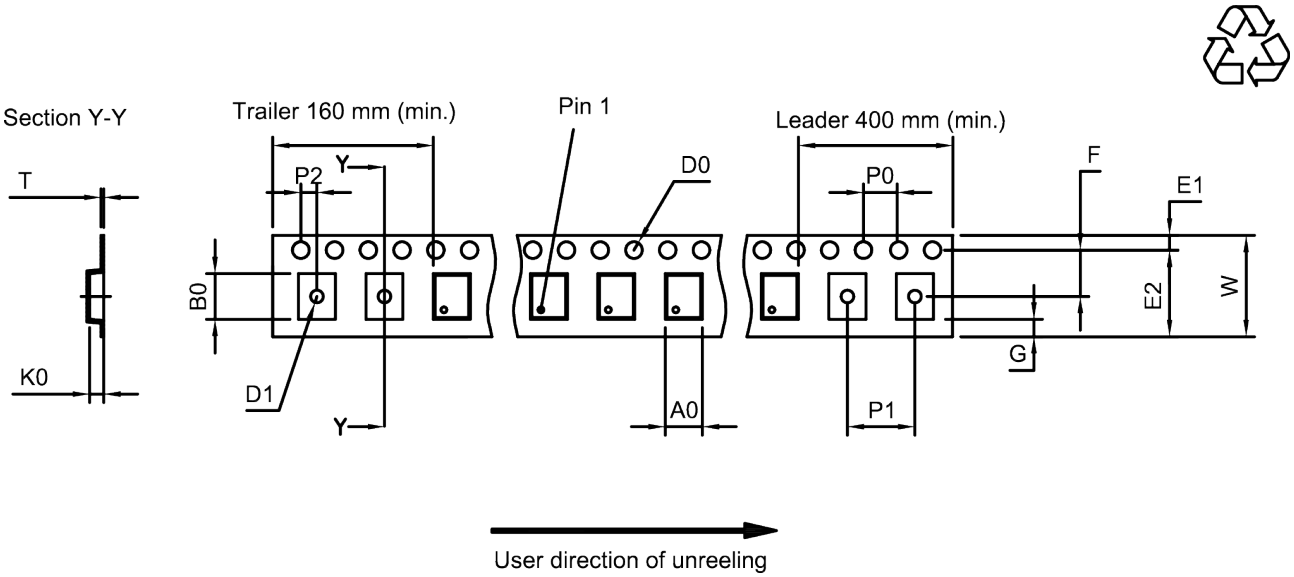

Figure 20: Drawing of tape (first-angle projection) for illustration only and not to scale. The valid tape dimensions are listed in Table 1.

A_0	2.25±0.1 mm
B_0	2.80±0.1 mm
D_0	$1.5^{+0.1/-0}$ mm
D_1	1.0 mm (min.)
E_1	$1.75_{\pm 0.1}$ mm

E_2	$6.25^{+0.2/-0}$ mm
F	$3.5_{\pm 0.05}$ mm
G	0.75 mm (min.)
K_0	$0.75_{\pm 0.05}$ mm
P_0	$4.0_{\pm 0.1}$ mm

P_1	$4.0_{\pm 0.1}$ mm
P_2	$2.0_{\pm 0.1}$ mm
T	$0.25_{\pm 0.05}$ mm
W	$8.0^{+0.3/-0.1}$ mm

Table 1: Tape dimensions.

17.2 Reel with diameter of 180 mm

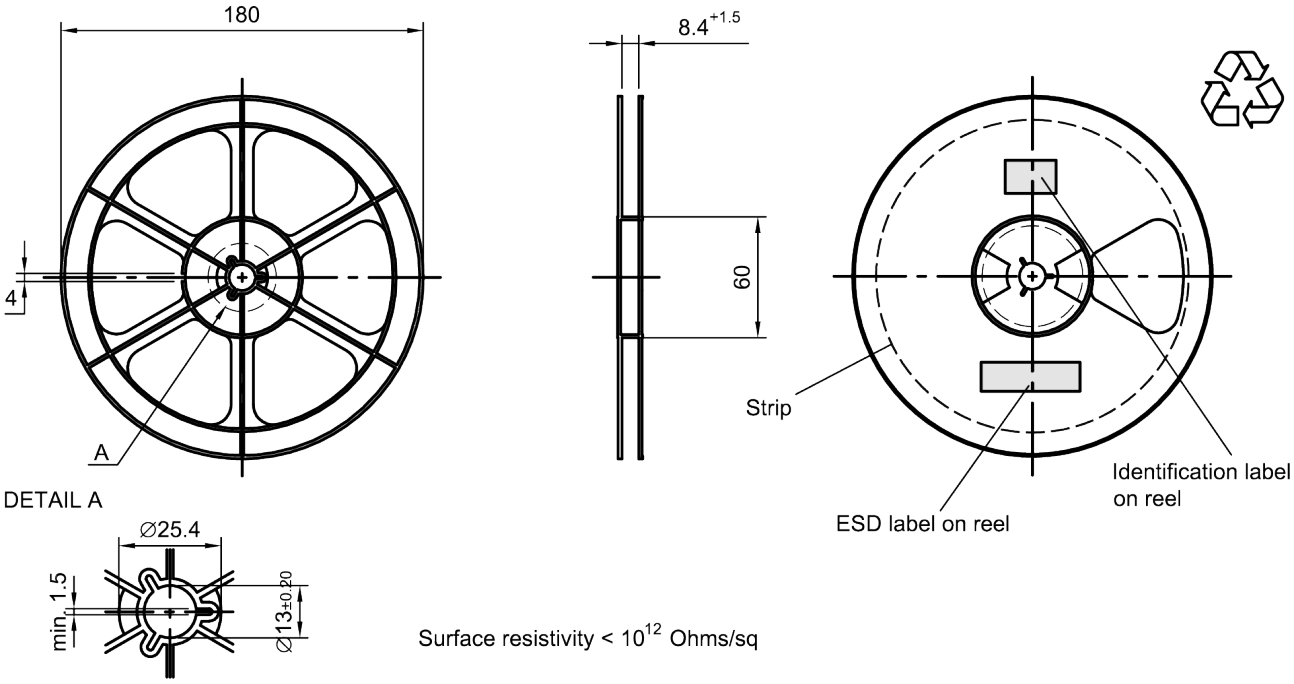

Figure 21: Drawing of reel (first-angle projection) with diameter of 180 mm.

Dimensions [mm]
X = 220+5
Y = 235+5
Sealing area 10±3

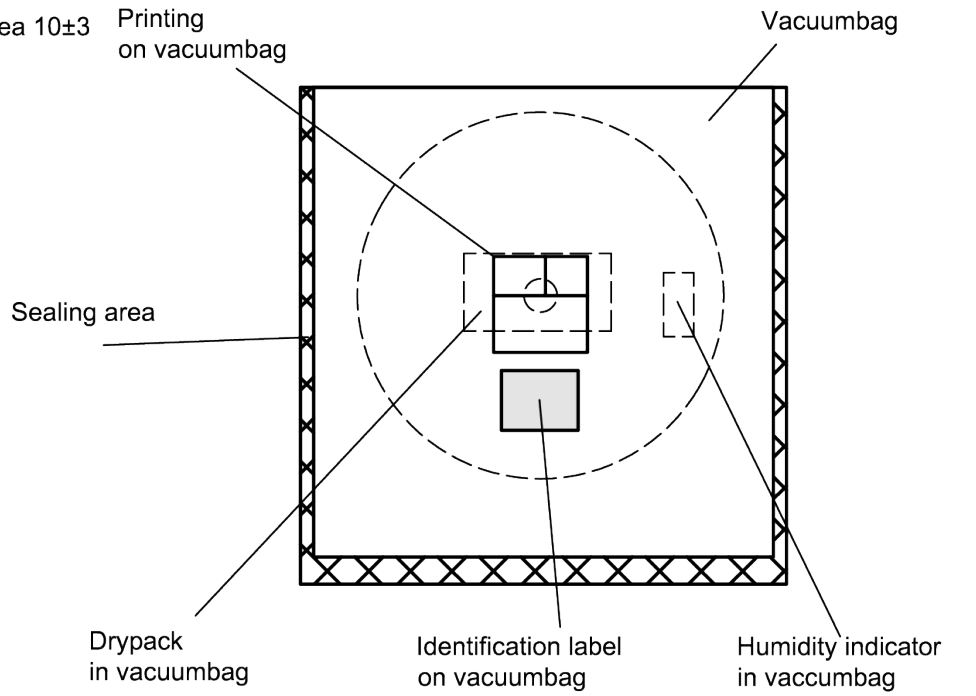

Figure 22: Drawing of moisture barrier bag (MBB) for reel with diameter of 180 mm.

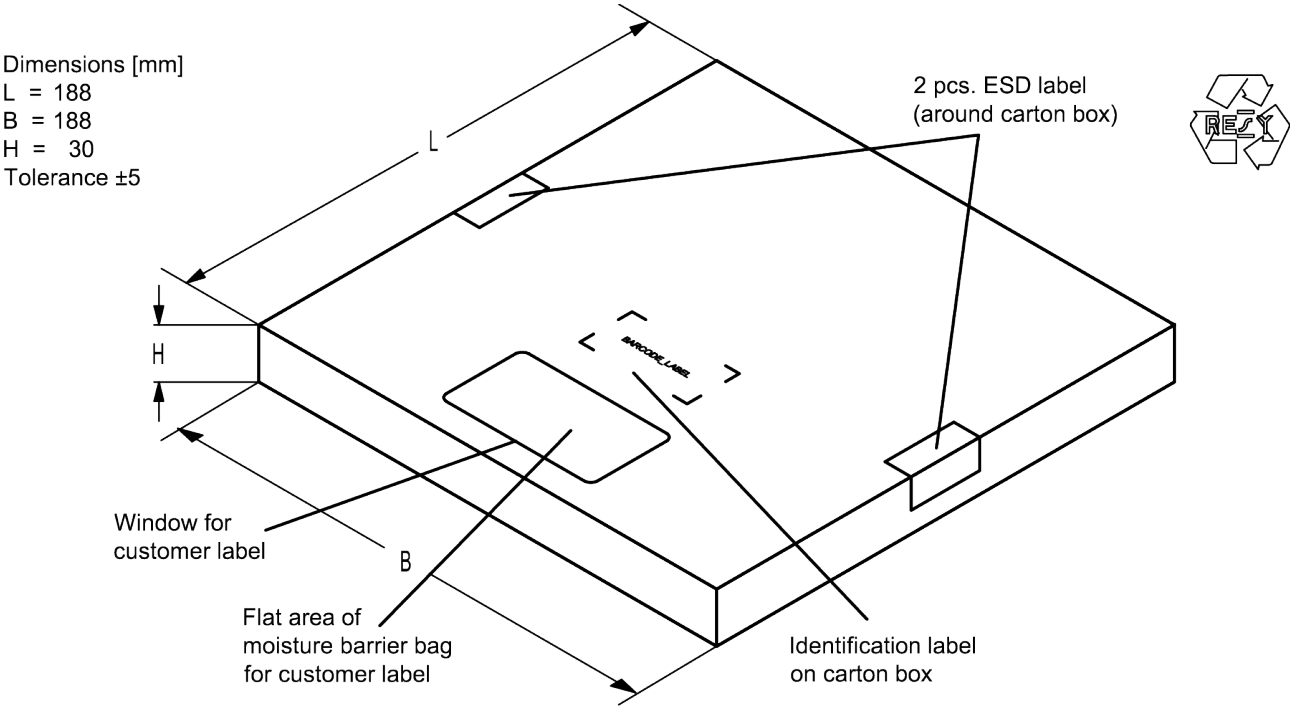

Figure 23: Drawing of folding box for reel with diameter of 180 mm.

17.3 Reel with diameter of 330 mm

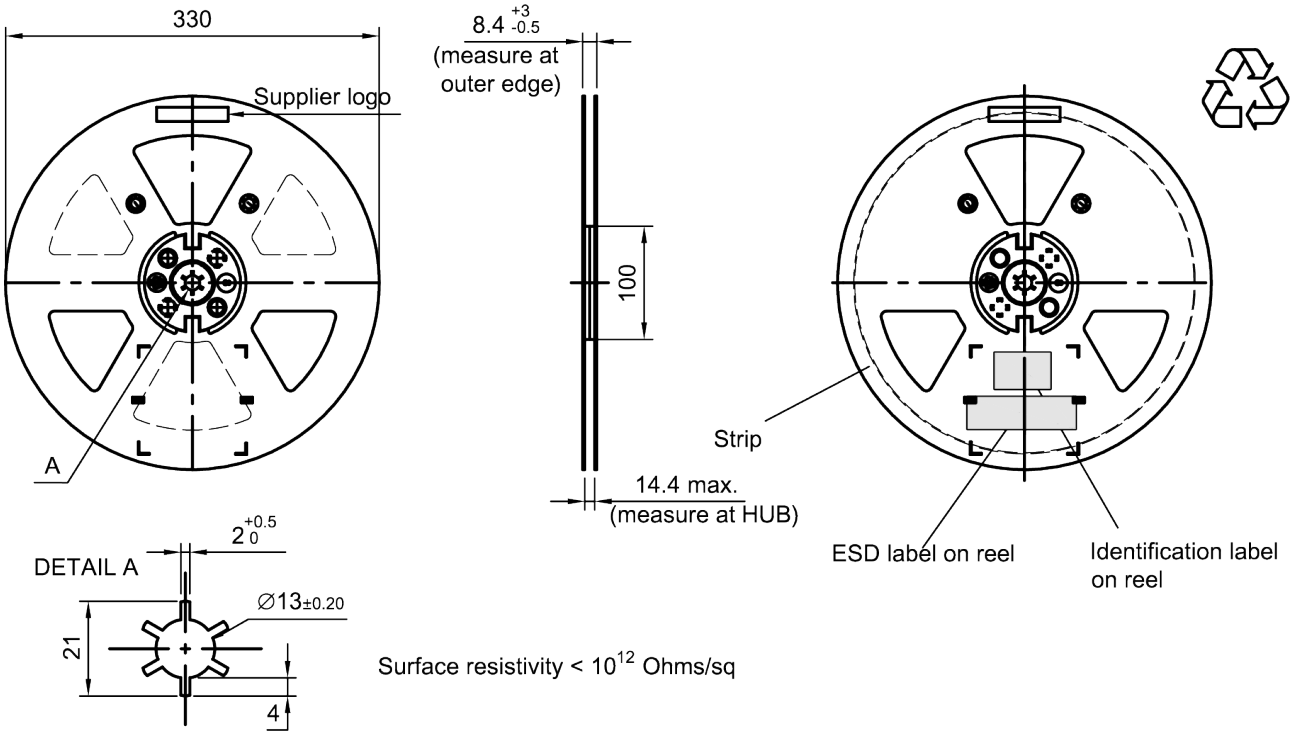

Figure 24: Drawing of reel (first-angle projection) with diameter of 330 mm.

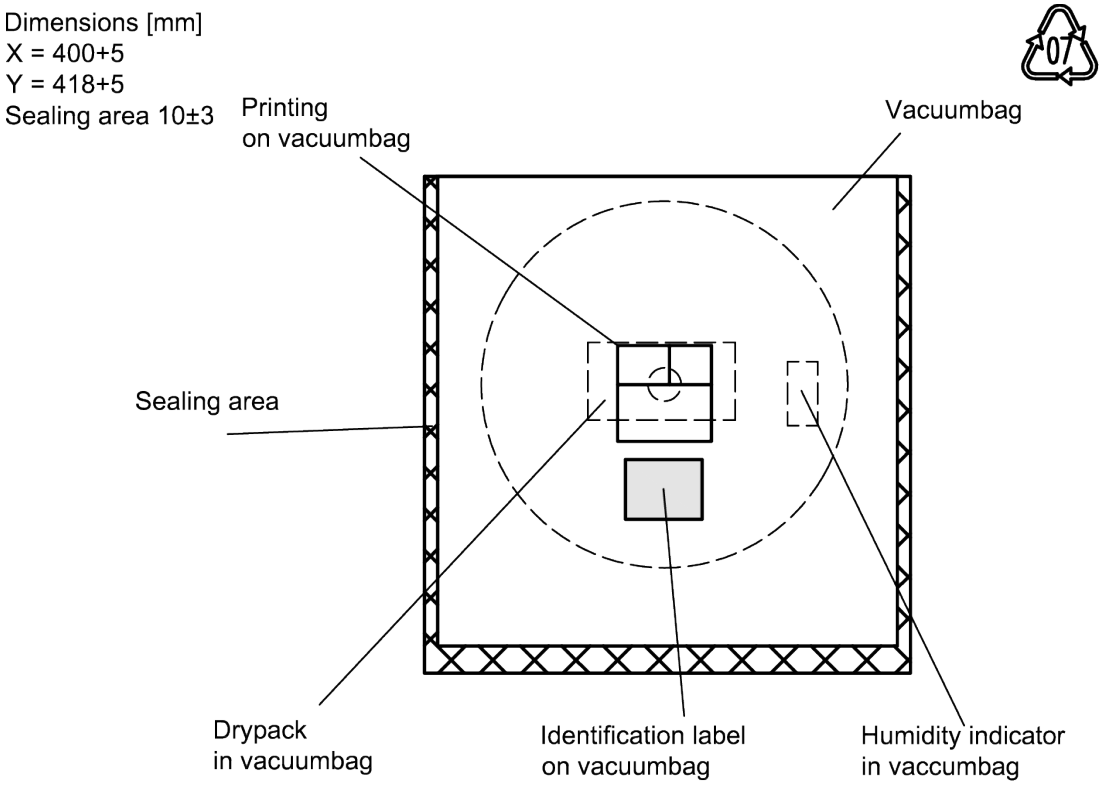

Figure 25: Drawing of moisture barrier bag (MBB) for reel with diameter of 330 mm.

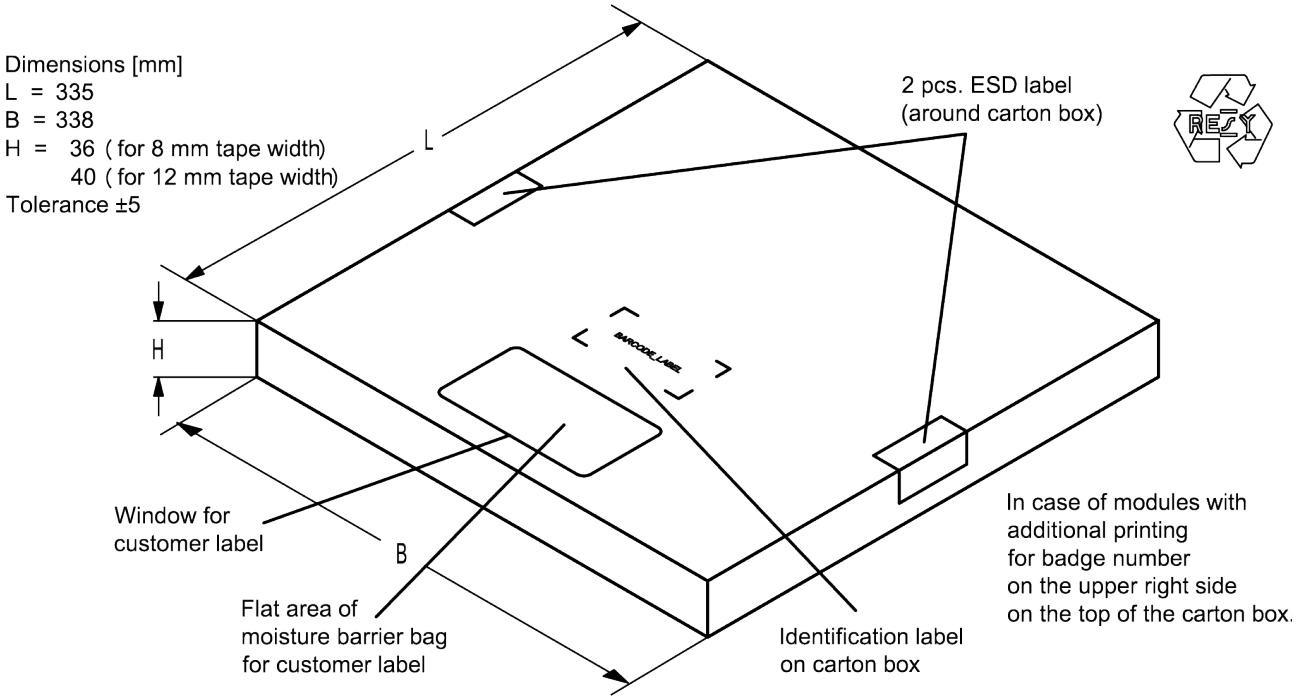

Figure 26: Drawing of folding box for reel with diameter of 330 mm.

18 Marking

Products are marked with product type number and lot number encoded according to Table 2:

- Type number:

  The 4 digit type number of the ordering code, e.g., B3xxxxB**1234**xxxx,
  is encoded by a special BASE32 code into a 3 digit marking.

  Example of decoding type number marking on device => in decimal code.
  16J => **1234**
  1 x 32^2 + **6** x 32^1 + **18 (=J)** x 32^0 = **1234**
  The BASE32 code for product type B8927 is 8PZ.

- Lot number:

  The last 5 digits of the lot number, e.g., **12345**,
  are encoded based on a special BASE47 code into a 3 digit marking.

  Example of decoding lot number marking on device in decimal code.
  5UY => **12345**
  5 x 47^2 + **27 (=U)** x 47^1 + **31 (=Y)** x 47^0 = **12345**

Adopted BASE32 code for type number			
Decimal value	Base32 code	Decimal value	Base32 code
0	0	16	G
1	1	17	H
2	2	18	J
3	3	19	K
4	4	20	M
5	5	21	N
6	6	22	P
7	7	23	Q
8	8	24	R
9	9	25	S
10	A	26	T
11	B	27	V
12	C	28	W
13	D	29	X
14	E	30	Y
15	F	31	Z

Adopted BASE47 code for lot number			
Decimal value	Base47 code	Decimal value	Base47 code
0	0	24	R
1	1	25	S
2	2	26	T
3	3	27	U
4	4	28	V
5	5	29	W
6	6	30	X
7	7	31	Y
8	8	32	Z
9	9	33	b
10	A	34	d
11	B	35	f
12	C	36	h
13	D	37	n
14	E	38	r
15	F	39	t
16	G	40	v
17	H	41	\
18	J	42	?
19	K	43	{
20	L	44	}
21	M	45	<
22	N	46	>
23	P		

Table 2: Lists for encoding and decoding of marking.

19 Soldering profile

The recommended soldering process is in accordance with IEC 60068-2-58 – 3rd edit and IPC/JEDEC J-STD-020B.

ramp rate	≤ 3 K/s
preheat	125 °C to 220 °C, 150 s to 210 s, 0.4 K/s to 1.0 K/s
T > 220 °C	30 s to 70 s
T > 230 °C	min. 10 s
T > 245 °C	max. 20 s
T ≥ 255 °C	–
peak temperature T_{peak}	250 °C +0/-5 °C
wetting temperature T_{min}	230 °C +5/-0 °C for 10 s ± 1 s
cooling rate	≤ 3 K/s
soldering temperature T	measured at solder pads

Table 3: Characteristics of recommended soldering profile for lead-free solder (Sn95.5Ag3.8Cu0.7).

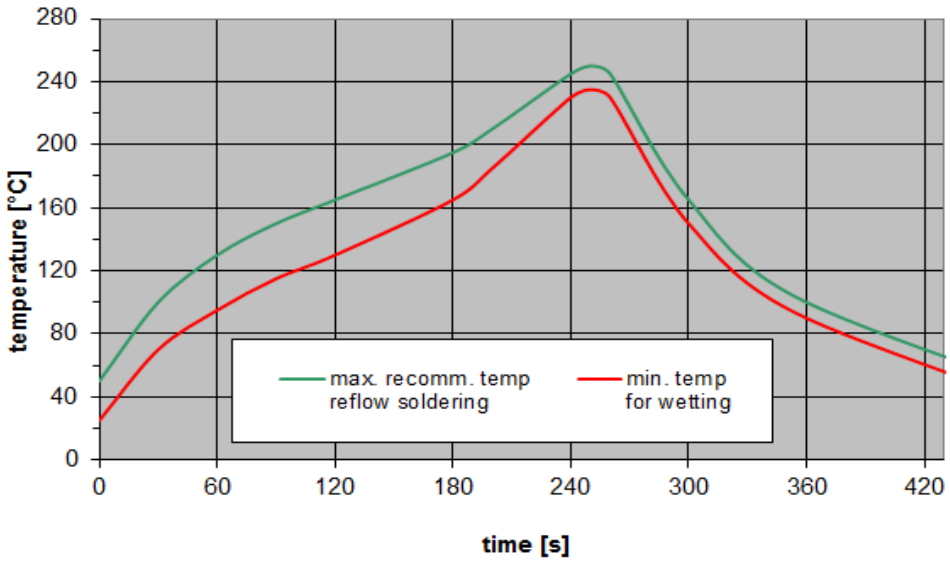

Figure 27: Recommended reflow profile for convection and infrared soldering – lead-free solder.

20 Annotations

20.1 RoHS compatibility

ROHS-compatible means that products are compatible with the requirements according to Art. 4 (substance restrictions) of Directive 2011/65/EU of the European Parliament and of the Council of June 8th, 2011, on the restriction of the use of certain hazardous substances in electrical and electronic equipment ("Directive") with due regard to the application of exemptions as per Annex III of the Directive in certain cases.

20.2 Scattering parameters (S-parameters)

The pin/port assignment is available in the headers of the S-parameter files. Please contact your local RF360 sales office.

20.3 Ordering codes and packing units

Ordering code	Packing unit
B39212B8927P810	15000 pcs
B39212B8927P810S 5	5000 pcs

Table 4: Ordering codes and packing units.

21 Cautions and warnings

21.1 Display of ordering codes for RF360 products

The ordering code for one and the same product can be represented differently in data sheets, data books, other publications and the website of RF360, or in order-related documents such as shipping notes, order confirmations and product labels. The varying representations of the ordering codes are due to different processes employed and do not affect the specifications of the respective products. Detailed information can be found on the Internet under https://rffe.qualcomm.com/.

21.2 Material information

Due to technical requirements components may contain dangerous substances. For information on the type in question please also contact one of our sales offices.

For information on recycling of tapes and reels please contact one of our sales offices.

21.3 Moldability

Before using in overmolding environment, please contact your local RF360 sales office.

21.4 Package information

Landing area

The printed circuit board (PCB) land pattern (landing area) shown is based on RF360 internal development and empirical data and illustrated for example purposes, only. As customers' SMD assembly processes may have a plenty of variants and influence factors which are not under control or knowledge of RF360, additional careful process development on customer side is necessary and strongly recommended in order to achieve best soldering results tailored to the particular customer needs.

Dimensions

Unless otherwise specified all dimensions are understood using unit millimeter (mm).

Projection method

Unless otherwise specified first-angle projection is applied.

22 Important notes

The following applies to all products named in this publication:

1. Some parts of this publication contain **statements about the suitability of our products for certain areas of application**. These statements are based on our knowledge of typical requirements that are often placed on our products in the areas of application concerned. We nevertheless expressly point out **that such statements cannot be regarded as binding statements about the suitability of our products for a particular customer application.** As a rule, RF360 Europe GmbH and its affiliates are either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always ultimately incumbent on the customer to check and decide whether an RF360 product with the properties described in the product specification is suitable for use in a particular customer application.
2. We also point out that **in individual cases, a malfunction of electronic components or failure before the end of their usual service life cannot be completely ruled out in the current state of the art, even if they are operated as specified.** In customer applications requiring a very high level of operational safety and especially in customer applications in which the malfunction or failure of an electronic component could endanger human life or health (e.g. in accident prevention or life-saving systems), it must therefore be ensured by means of suitable design of the customer application or other action taken by the customer (e.g. installation of protective circuitry or redundancy) that no injury or damage is sustained by third parties in the event of malfunction or failure of an electronic component.
3. **The warnings, cautions and product-specific notes must be observed.**
4. In order to satisfy certain technical requirements, **some of the products described in this publication may contain substances subject to restrictions in certain jurisdictions (e.g. because they are classed as hazardous)**. Useful information on this will be found in our Material Data Sheets on the Internet (https://rffe.qualcomm.com). Should you have any more detailed questions, please contact our sales offices.
5. We constantly strive to improve our products. Consequently, **the products described in this publication may change from time to time**. The same is true of the corresponding product specifications. Please check therefore to what extent product descriptions and specifications contained in this publication are still applicable before or when you place an order. We also **reserve the right to discontinue production and delivery of products**. Consequently, we cannot guarantee that all products named in this publication will always be available.
   The aforementioned does not apply in the case of individual agreements deviating from the foregoing for customer-specific products.

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